Old Company Name in Catalogs and Other Documents

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Renesas Electronics website: http://www.renesas.com

April 1st, 2010 Renesas Electronics Corporation

Issued by: Renesas Electronics Corporation (http://www.renesas.com)

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2SK1526, 2SK1527

Silicon N Channel MOS FET

REJ03G0950-0300 Rev.3.00 May 13, 2009

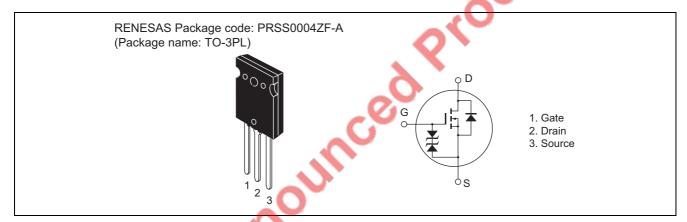
Application

High speed power switching

Features

- Low on-resistance
- High speed switching
- · Low drive current
- No secondary breakdown
- Suitable for switching regulator and DC-DC converter

Outline



Absolute Maximum Ratings

 $(Ta = 25^{\circ}C)$

Item	Symbol	Ratings	Unit	
Drain to source voltage 2SK1526	V _{DSS}	450	V	
2SK1527		500		
Gate to source voltage	V_{GSS}	±30	V	
Drain current	I _D	40	А	
Drain peak current	I _{D(pulse)} *1	160	А	
Body to drain diode reverse drain current	I _{DR}	40	А	
Channel dissipation	Pch*2	250	W	
Channel temperature	Tch	150	°C	
Storage temperature	Tstg	−55 to +150	°C	

Notes: 1. PW \leq 10 μ s, duty cycle \leq 1%

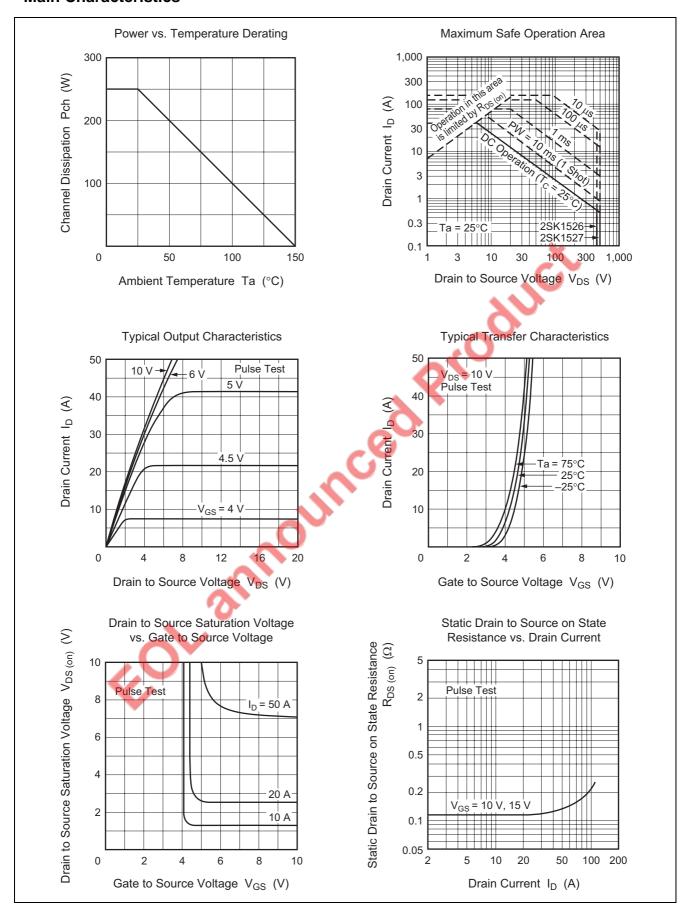
2. Value at $T_C = 25$ °C

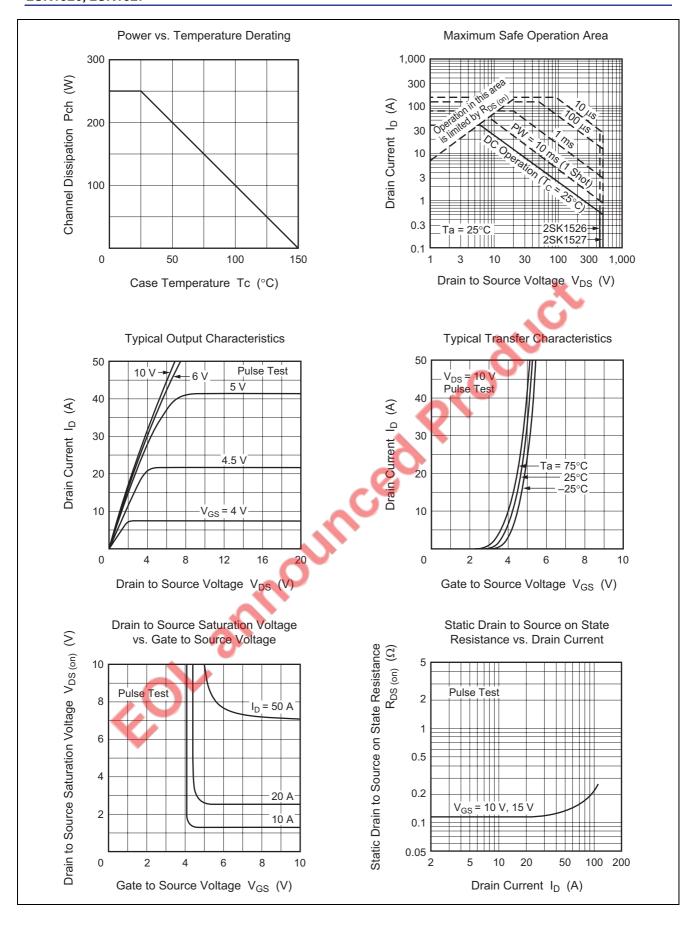
Electrical Characteristics

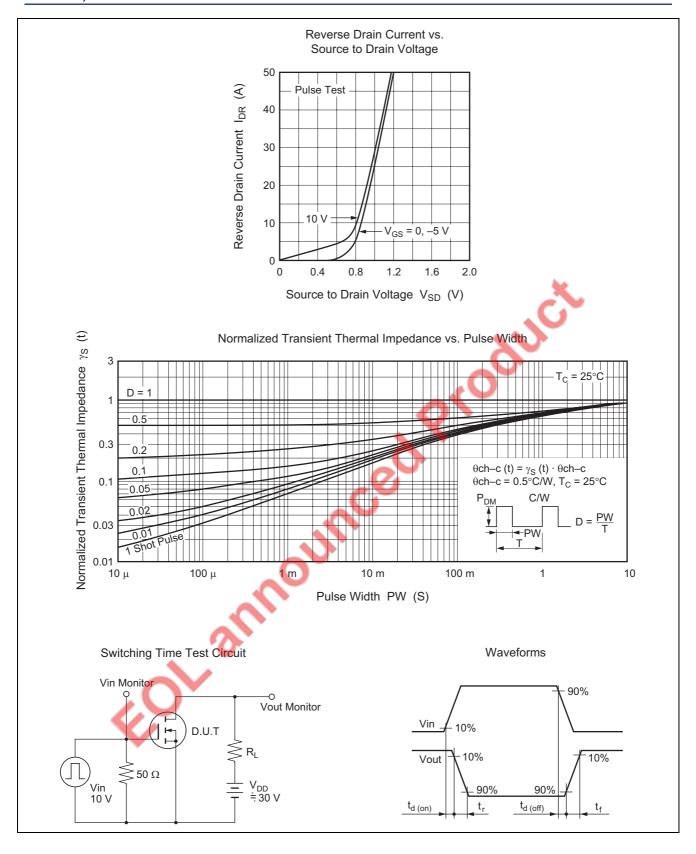
 $(Ta = 25^{\circ}C)$

Drain to source 2SK1526 ZSK1527 S500 S50			Symbol	Min	Тур	Max	Unit	Test conditions
Gate to source breakdown voltage V_{(BR)GSS} ±30	Drain to source	2SK1526	V _{(BR)DSS}	450	_	_	V	$I_D = 10 \text{ mA}, V_{GS} = 0$
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$		2SK1527	1	500	1			
Zero gate voltage drain current $\frac{2SK1526}{2SK1527}$ $\frac{1}{2SK1527}$ $\frac{1}{2SK1527}$ $\frac{1}{2SK1527}$ $\frac{1}{2SK1527}$ $\frac{1}{2SK1527}$ $\frac{1}{2SK1527}$ $\frac{1}{2SK1527}$ $\frac{1}{2SK1526}$ $\frac{1}{2SK1526}$ $\frac{1}{2SK1526}$ $\frac{1}{2SK1526}$ $\frac{1}{2SK1527}$ $\frac{1}{$	Gate to source breakdov	vn voltage	V _{(BR)GSS}	±30	_	_	V	$I_G = \pm 100 \ \mu A, \ V_{DS} = 0$
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$			_	_	_	±10	μΑ	$V_{GS} = \pm 25 \text{ V}, V_{DS} = 0$
Sate to source cutoff voltage Vos(off) 2.0 - 3.0 V Io = 1 mA, Vos = 10 V	Zero gate voltage drain	2SK1526	I _{DSS}	_	_	250	μΑ	$V_{DS} = 360 \text{ V}, V_{GS} = 0$
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	current	2SK1527						$V_{DS} = 400 \text{ V}, V_{GS} = 0$
State resistance 2SK1527 - 0.12 0.16	Gate to source cutoff vol	tage	$V_{GS(off)}$	2.0	_	3.0	V	I _D = 1 mA, V _{DS} = 10 V
Forward transfer admittance $ y_{fs} = 20 - 30 - S - S = 10 = 20 \text{ A}, V_{DS} = 10 \text{ V}^{+3}$ Input capacitance $ y_{fs} = 20 - 5800 - S = 10 \text{ V}, V_{QS} = 0$, Output capacitance $ y_{fs} = 10 - 20 \text{ A}, V_{DS} = 10 \text{ V}^{+3}$ Turn-on delay time $ y_{fs} = 150 - S = 150 - S = 10 $	Static drain to source on	2SK1526	1	_	0.11	0.15	Ω	$I_D = 20 \text{ A}, V_{GS} = 10 \text{ V}^{*3}$
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	state resistance	2SK1527		_	0.12	0.16		
Output capacitance Coss	Forward transfer admitta	ince	y _{fs}	20	30	_	S	$I_D = 20 \text{ A}, V_{DS} = 10 \text{ V}^{*3}$
Reverse transfer capacitance Crss — 150 — pF Turn-on delay time $t_{d(on)}$ — 60 — ns t_{D} = 20 A, V_{GS} = 10 V, Rise time t_{r} — 175 — ns Turn-off delay time $t_{d(off)}$ — 420 — ns Fall time t_{r} — 160 — ns Body to drain diode forward voltage V_{DF} — 1.2 — V t_{DF} — 1.2 — V t_{DF} — ns t_{CS} = 0 Note: 3. Pulse test	Input capacitance			_	5800	_	pF	
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	Output capacitance		Coss	_	1430	_	pF	f = 1 MHz
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$		ance	1	_		_	·	
Rise time t_r — 175 — ns $R_L = 1.5 \Omega$ Turn-off delay time t_d_{doff} — 420 — ns Fall time t_t — 160 — ns Body to drain diode forward voltage V_{DF} — 1.2 — V_{DF} Ir = 40 A, $V_{GS} = 0$ Body to drain diode reverse recovery t_{rr} — 600 — ns $t_{F} = 40 \text{A}$, $t_{CS} = 0$, $t_{CS} = 0$, $t_{CS} = 0$, $t_{CS} = 0$ and $t_{CS} = 0$. Note: 3. Pulse test	· · · · · · · · · · · · · · · · · · ·		t _{d(on)}	_	60	_	ns	$I_D = 20 \text{ A}, V_{GS} = 10 \text{ V},$
Fall time t_f — 160 — ns Body to drain diode forward voltage V_{DF} — 1.2 — V $I_F = 40 \text{ A}, V_{GS} = 0$ Body to drain diode reverse recovery t_{rr} — 600 — ns $I_F = 40 \text{ A}, V_{GS} = 0, time$ Note: 3. Pulse test	-			_	175	_	ns	
Fall time t_f — 160 — ns Body to drain diode forward voltage V_{DF} — 1.2 — V $I_F = 40 \text{ A}, V_{GS} = 0$ Body to drain diode reverse recovery t_{rr} — 600 — ns $I_F = 40 \text{ A}, V_{GS} = 0, time$ Note: 3. Pulse test	Turn-off delay time			_	420	_	ns	
Body to drain diode forward voltage V_{DF} — 1.2 — V $I_F = 40 \text{ A}, V_{GS} = 0$ Body to drain diode reverse recovery t_{rr} — 600 — ns $I_F = 40 \text{ A}, V_{GS} = 0$, t_{rr} time Note: 3. Pulse test	·			_	160	_	ns	
Body to drain diode reverse recovery t_{rr} — 600 — ns $I_F = 40 \text{ A}$, $V_{GS} = 0$, $d_{IF}/dt = 100 \text{ A}/\mu\text{s}$		ard voltage		_				I _F = 40 A, V _{GS} = 0
time Note: 3. Pulse test	-			_		4	ns	
Note: 3. Pulse test						X		

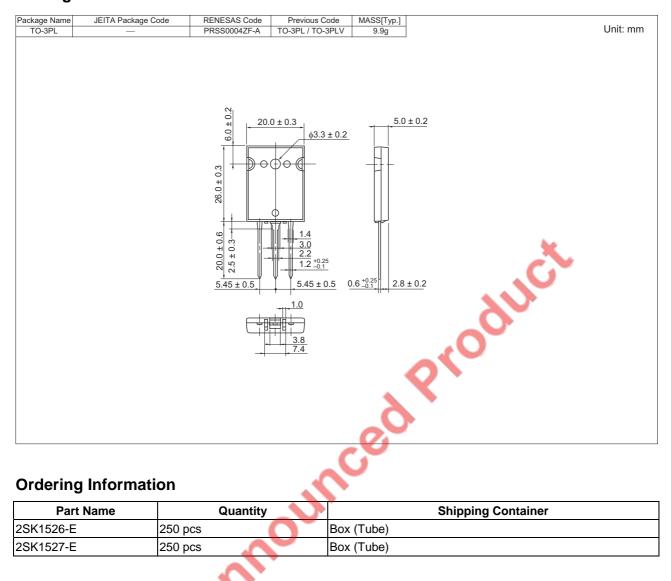
Main Characteristics







Package Dimensions



Ordering Information

Part Name	Quantity	~	Shipping Container
2SK1526-E	250 pcs		Box (Tube)
2SK1527-E	250 pcs		Box (Tube)

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